

10.3Gb/s SFP+ Transceiver

APSP55HM3xDL40





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ATOP's APSP55HM3xDL40 Small Form Factor Pluggable (SFP+) transceivers are compatible with SFF-8431,SFF-8432 and support 10G Ethernet ER and 10G Fibre Channel . It is designed for use in 10G-Gigabit multi-rate links up to 40km of G.652 . Digital diagnostics functions are available via a 2-wire serial interface as specified in SFF-8472.

Product Features

- ✓ Supports 9.95 to 11.3Gb/s
- ✓ Duplex LC connector
- √ Hot-pluggable SFP footprint
- ✓ Cooled 1550nm EML laser
- \checkmark RoHS compliant and Lead Free
- ✓ 40km link length
- ✓ Metal enclosure for lower EMI
- ✓ Built-in dual CDR
- ✓ Power dissipation
- \checkmark <2.0W (0~70°C),<2.3W(0~85°C) , <2.3W(-40~85°C)
- ✓ Commercial and industrial operating temperature optional
- ✓ SFP MSA SFF-8472 SFF-8431 SFF-8432 IEEE 802.3 Compliant

Applications

- ✓ 10G Ethernet ER and 10G Fibre Channel
- ✓ OTN G.709 OTU1e/2/2e FEC bit rates
- ✓ SDH STM-64



Product Selection

Part Number	Operating Case temperature	DDMI
APSP55HM3CDL40	Commercial(0~+70°C)	Yes
APSP55HM3EDL40	Extend(0~+85℃)	Yes
APSP55HM3IDL40	Industrial(-40~85 °C)	Yes



Regulatory Compliance

- ESD to the Electrical PINs: compatible with MIL-STD-883 Method 3015
- ESD to the Duplex LC Receptacle: compatible with EN 61000-4-2
- Immunity compatible with EN 61000-4-3
- EMI compatible with FCC Part 15 Class B
- Laser Eye Safety compatible with FDA 21CFR 1040.10 and 1040.11 IEC 60950, IEC60825-1,2
- RoHS compliant with RoHS 2.0(2015/863/EU)-amending.

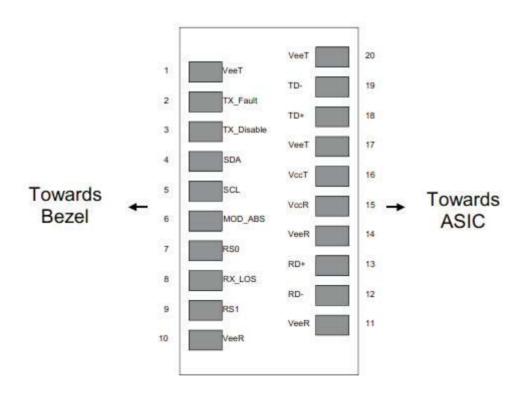
Pin Descriptions

Pin	Symbol	Name	Ref.
1	VeeT	Transmitter Ground (Common with Receiver Ground)	1
2	TX Fault	Transmitter Fault. LVTTL-O	2
3	TX Disable	Transmitter Disable. Laser output disabled on high or open. LVTTL-I	3
4	SDA	2-Wire Serial Interface Data Line (Same as MOD-DEF2 in INF-8074i). LVTTL-I/O	2
5	SCL	2-Wire Serial Interface Data Line (Same as MOD-DEF2 in INF-8074i). LVTTL-I	2
6	Mod_ABS	Module Absent, Connect to VeeT or VeeR in Module.	2
7	RS0	Rate Select 0, optionally controls SFP+ module receiver LVTTL-I	4
8	LOS	Loss of Signal indication. Logic 0 indicates normal operation. LVTTL-O	5
9	RS1	Rate Select 1, optionally controls SFP+ module transmitter. LVTTL-I	4
10	VeeR	Receiver Ground (Common with Transmitter Ground)	1
11	VeeR	Receiver Ground (Common with Transmitter Ground)	1
12	RD-	Receiver Inverted DATA out. AC Coupled. CML-O	
13	RD+	Receiver Non-inverted DATA out. AC Coupled. CML-O	
14	VeeR	Receiver Ground (Common with Transmitter Ground)	1
15	VccR	Receiver Power Supply	6
16	VccT	Transmitter Power Supply	6
17	VeeT	Transmitter Ground (Common with Receiver Ground)	1
18	TD+	Transmitter Non-Inverted DATA in. AC Coupled. CML- I	
19	TD-	Transmitter Inverted DATA in. AC Coupled. CML- I	
20	VeeT	Transmitter Ground (Common with Receiver Ground)	1



Note

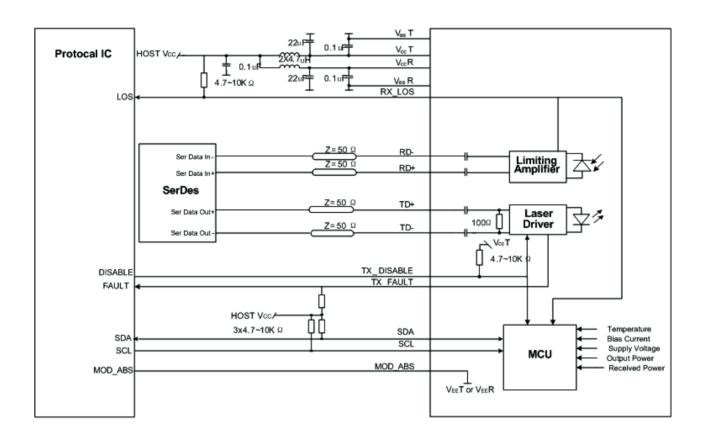
- 1. Circuit ground is internally isolated from chassis ground.
- 2. TX Fault is an open collector/drain output .Which should be pulled up with a 4.7K 10K Ohms resistor on the host board if intended for use. Pull up voltage should be between 2.0V to Vcc+0.3V.A high output indicates a transmitter fault caused by either the tx bias current or the tx output power exceeding the preset alarm thresholds. A low output indicates normal operation .In the low state, the output is pulled to <0.8V.
- 3. Laser output disabled on TX Disable > 2.0V or open, enabled on TX Disable < 0.8V.
- 4. Internally pulled down per SFF-8431 Rev4.1.
- 5. LOS is open collector output. Should be pulled up with 4.7k 10kohms on host board to a voltage between 2.0V and 3.6V. Logic 0 indicates normal operation; logic 1 indicates loss of signal.
- 6. Internally connected



Pin-out of Connector Block on Host Board



Recommend Circuit Schematic



Absolute Maximum Ratings

Parameter	Symbol	Min	Тур	Max	Unit	Ref.
Maximum Supply Voltage	Vcc	-0.5		+4.0	V	
Storage Temperature	TS	-40		+85	°C	
Operating Humidity	RH	0		85	%	



Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit	Ref.
Power Supply Voltage	Vcc	3.13	3.30	3.47	V	
	lcc			600	mA	Commercial
Power Supply Current	lcc			700	mA	Extend
	lcc			700	mA	Industrial
	Tc	0		+70	°C	Commercial
Case Operating Temperature	Te	0		+85	°C	Extend
	TI	-40		+85	°C	Industrial
Bit Rate	Br	9.95		11.3	Gbps	
9/125um G.652 SMF	Lmax			40	km	

Electrical Characteristics

Parameter	Symbol	Min	Тур	Max	Unit	Ref.
Transmitter						
Input differential impedance	Rin	80	100	120	Ω	1
Differential data input swing	Vin, pp	120		850	mV	
TX Disable-High		Vcc – 0.8		Vcc	V	
TX Disable-Low		Vee		Vee+ 0.8	V	
TX Fault-High		Vcc-0.8		Vcc	V	
TX Fault-Low		Vee		Vee+0.8	V	
Receiver						
Differential data output swing	Vout, pp	300		850	mV	2
Data output rise time	Tr	28			ps	3
Data output fall time	Tf	28			ps	3
LOS-High		Vcc – 0.8		Vcc	V	
LOS-Low		Vee		Vee+0.8	V	

Notes:

- 1. AC coupled.
- 2. Into 100 ohm differential termination.
- 3. 20 80 %



Optical Characteristics

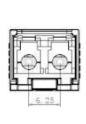
Receiver Overload -1 dBm Optical Center Wavelength λC 1260 1600 nm	Parameter	Symbol	Min	Тур	Max	Unit	Ref.
Optical Wavelength λ 1530 1565 nm Side-Mode Suppression Ratio SMSR 30 dB RMS Spectral Width(-20dB) σ 1 nm Relative Intensity Noise RIN -128 dB/Hz Path penalty at 800ps/nm@9.95Gb/s 2 dB Optical Extinction Ratio ER 8.2 dB Receiver RX Sensitivity @10.3Gb/s SENS -15.8 dBm 1,2 Receiver Overload -1 dBm Optical Center Wavelength λC 1260 1600 nm	Transmitter						
Side-Mode Suppression Ratio SMSR 30 dB dB RMS Spectral Width(-20dB) σ 1 nm dB Relative Intensity Noise RIN -128 dB/Hz dB Path penalty at 800ps/nm@9.95Gb/s 2 dB dB Optical Extinction Ratio ER 8.2 dB dB Receiver RX Sensitivity @10.3Gb/s SENS -15.8 dBm 1,2 Receiver Overload -1 dBm dBm 1,2 Optical Center Wavelength λC 1260 1600 nm	Output Opt. Power	РО	-3		+4	dBm	
RMS Spectral Width(-20dB) σ 1 nm Relative Intensity Noise RIN -128 dB/Hz Path penalty at 800ps/nm@9.95Gb/s 2 dB Optical Extinction Ratio ER 8.2 dB Receiver RX Sensitivity @10.3Gb/s SENS -15.8 dBm 1.2 Receiver Overload -1 dBm Optical Center Wavelength λ C 1260 1600 nm	Optical Wavelength	λ	1530		1565	nm	
Relative Intensity Noise RIN -128 dB/Hz Path penalty at 800ps/nm@9.95Gb/s 2 dB Optical Extinction Ratio ER 8.2 dB Receiver RX Sensitivity @10.3Gb/s SENS -15.8 dBm 1,2 Receiver Overload -1 dBm Optical Center Wavelength λC 1260 1600 nm	Side-Mode Suppression Ratio	SMSR	30			dB	
Path penalty at 800ps/nm@9.95Gb/s 2 dB Optical Extinction Ratio ER 8.2 dB Receiver RX Sensitivity @10.3Gb/s SENS -15.8 dBm 1,2 Receiver Overload -1 dBm 0 0 Optical Center Wavelength λC 1260 1600 nm 1	RMS Spectral Width(-20dB)	σ			1	nm	
Optical Extinction Ratio ER 8.2 dB Receiver -15.8 dBm 1,2 RX Sensitivity @10.3Gb/s SENS -15.8 dBm 1,2 Receiver Overload -1 dBm -1 Optical Center Wavelength λC 1260 1600 nm	Relative Intensity Noise	RIN			-128	dB/Hz	
Receiver RX Sensitivity @10.3Gb/s SENS -15.8 dBm 1,2 Receiver Overload -1 dBm dBm Optical Center Wavelength λC 1260 1600 nm	Path penalty at 800ps/nm@9.95Gb/s				2	dB	
RX Sensitivity @10.3Gb/s SENS -15.8 dBm 1,2 Receiver Overload -1 dBm Optical Center Wavelength λC 1260 1600 nm	Optical Extinction Ratio	ER	8.2			dB	
Receiver Overload -1 dBm Optical Center Wavelength λC 1260 1600 nm	Receiver						
Optical Center Wavelength λC 1260 1600 nm	RX Sensitivity @10.3Gb/s	SENS			-15.8	dBm	1,2
	Receiver Overload		-1			dBm	
LOS De-Assert LOSD -20 dRm	Optical Center Wavelength	λC	1260		1600	nm	
200 De 7,05ct C	LOS De-Assert	LOSD			-20	dBm	
LOS Assert LOSA -34 dBm	LOS Assert	LOSA	-34			dBm	
LOS Hysteresis 0.5 dB	LOS Hysteresis		0.5			dB	

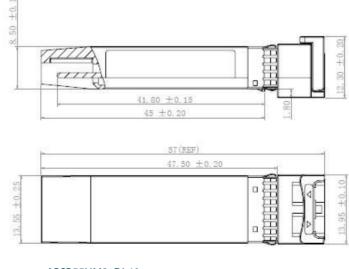
Notes:

- 1. Measured with conformance signals defined in FC-PI-2 Rev. 10.0 specifications.
- 2.Measured with PRBS 2³¹-1 at 10⁻¹²BER.

Mechanical Specifications

• ATOP's Small Form Factor Pluggable (SFP+) transceivers are compatible with the dimensions defined by the SFP Multi-Sourcing Agreement (MSA) .



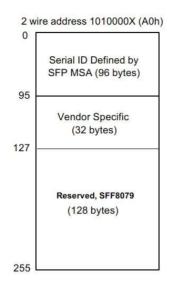


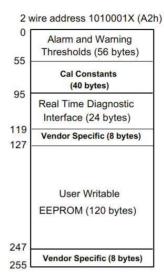
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EEPROM Information

• EEPROM memory map specific data field description is as below:





Digital Diagnostic Monitoring Interface

Five transceiver parameter values are monitored. The following table defines the monitored parameter's accuracy.

Parameter	Range	Accuracy	Calibration
Temperature	0 to +70°C (C)	1200	leste med
	0 to +85°C (E)	±3°C	Internal
	-40 to +85°C (I)		
Voltage	2.97 to 3.63V	±3%	Internal
Bias Current	0 to 100mA	±10%	Internal
TX Power	-1 to 4dBm	±3dB	Internal
RX Power	-16 to-1dBm	±3dB	Internal

Revision History

Revision	Initiated	Reviewed	Approved	DCN	Release Date
Version1.0	Xiaoaiyou	Sunbin	Dingzheng	New Released.	July 28, 2016
Version1.1	Tangzhiqiang	Yangpeiyun	Dingzheng	Update the new template	Dec 19, 2019
Version1.2	Tangrong	Yangpeiyun	Dingzheng	Update the regulatory compliance	June 4, 2020



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